

1 **Supporting Information**

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3 **Carrier dynamics tailored by electron/hole trapping domains in**
4 **asymmetric graphitic carbon nitride for superior photocatalytic**
5 **hydrogen evolution**

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71 **S1. Experimental section**

72 **S1.1 Materials and chemical reagents**

73 Melamine (MA), cyanuric acid, triethanolamine (TEOA) and 2,2,6,6-tetramethylpiperidine-
74 1-oxyl (TEMPO) were purchased from Shanghai Aladdin Biochemical Technology Co., Ltd.
75 Barbituric acid (BA), chloroplatinic acid (H_2PtCl_6) were purchased from Shanghai Macklin
76 Biochemical Co., Ltd. The anhydrous ethanol was purchased from Tianjin Fuyu Fine Chemical
77 Co., Ltd. Sodium sulfate (Na_2SO_4) was purchased from Shanghai Yi'en chemical technology Co.,
78 Ltd. All the reagents were used without further purification. Ultrapure water was used
79 throughout the experiment.

80 **S1.2 Characterization**

81 The morphologies of the samples were obtained by scanning electron microscope (SEM,
82 JSM-7000F), and transmission electron microscope (TEM, JEM-2100). Powder X-ray diffraction
83 (XRD) analyses were collected on a Bruker D8 Advanced X-ray diffractometer using $\text{Cu K}\alpha$
84 radiation (40 KV, 40 mA). Fourier transform infrared (FTIR) spectra for all samples were
85 conducted by Bruker Tensor 27 spectrometer scanning. X-ray photoelectron spectroscopy
86 (XPS) and their valence-band spectra were recorded by a Thermofisher scalable 250xi
87 instrument equipped with an $\text{Al K}\alpha$ X-ray source. The elemental determinations were
88 measured by the element analyzer (UNICUBE - Elementar). The ^{13}C solid-state cross
89 polarization magic angle spinning nuclear magnetic resonance (CP-MAS NMR) spectra were
90 taken on a Bruker avance III 400 MHz. The Brunauer-Emmett-Teller (BET) surface areas of
91 samples were recorded by the nitrogen adsorption-desorption method at 77 K on a
92 Quantachrome apparatus. The pore size distribution curves were surveyed using the Barrett-
93 Joyner-Halenda (BJH) model. The photoluminescence (PL, FluoroMax-4P) spectra were
94 measured by a fluorescence spectrophotometer with an excitation wavelength of 350 nm.
95 Temperature-dependent PL spectra (FLS1000) were measured by at 80 K, 100 K, 120 K, 140 K,
96 160 K, 180 K, 200 K, 220 K, 260 K and 300 K. The femtosecond transient absorption
97 spectroscopy (fs-TA) was measured on a Helios pump-probe system from Ultrafast Systems
98 LLC coupled with an amplified femtosecond laser system from Coherent. The optical
99 parametric amplifier (TOPAS-800-fs) delivered a 350 nm pump pulse (~ 0.1 mW), which was
100 generated by a Ti-sapphire regenerative amplifier (800 nm, 35 fs, 6 mJ/pulse, and 1 kHz
101 repetition rate). The surface potentials were measured by in-situ KPFM on a Bruker Dimension
102 Icon. The samples were dispersed in ethanol via sonication, then spin-coated onto ITO for

103 testing. Subsequently, the contact potential differences of the samples were recorded under
104 dark and light irradiation, respectively. Contact angle measurements were taken on a KRUSS
105 DSA100 contact angle meter. UV-visible diffuse reflectance spectra (UV-vis DRS, LAMBDA950)
106 were recorded using a UV/vis/NIR spectrophotometer. Electron paramagnetic resonance
107 (EPR) analyses were detected on an EMX nano BRUKER spectrometer.

108 **S1.3 Photoelectrochemical test**

109 The photoelectrochemical properties, including Mott-Schottky plots (M-S), electrochemical
110 impedance spectra (EIS), and transient photocurrent response (TPR), and open circuit
111 potential-time plots (OCPT), cyclic voltammetry curves (CV), linear sweep voltammetry curves
112 (LSV) were evaluated in a 0.25 M Na₂SO₄ aqueous solution using an electrochemical
113 workstation (CHI660E) with a three-electrode system under simulated visible light irradiation.
114 The photocatalyst-coated F-doped tin oxide conductive glass (FTO), a Pt mesh, and an Ag/AgCl
115 electrode acted as the working electrode, the counter electrode, and the reference electrode,
116 respectively. The working electrode was prepared as follows: 10 mg of the photocatalyst was
117 dispersed in 1 mL of Nafion solution (5 wt%) with the assistance of ultrasound. Then, the slurry
118 was dropped onto a FTO with an exposed area of 1 cm × 1 cm and dried in the air to form a
119 working electrode.

120 **S1.4 Photocatalytic hydrogen evolution experiment**

121 Photocatalytic hydrogen evolution reactions of samples were carried out by an online
122 photocatalytic hydrogen generation system (Beijing Perfect-light Science & Technology Co.,
123 Ltd., China) with a 250 mL closed quartz reactor and a circulating water system. The light
124 source was a 300 W Xe lamp ($\lambda > 420$ nm, Beijing Perfect-light, PLS-SXE300). The experiment
125 process was described as follows: 50 mg of as-prepared samples were dispersed in 100 mL of
126 the aqueous solution containing TEOA (10 vol%) as an electron donor, with ultrasound for 20
127 min. The H₂PtCl₆ aqueous solution acted as the source of the cocatalyst (3 wt% Pt) and was
128 added to the suspension and irradiated for 60 min to ensure that the Pt was loaded tightly on
129 the photocatalyst surface. Afterward, the reaction vessel was completely degassed to remove
130 air before being further irradiated. The temperature of the reaction solution was maintained
131 at 6 °C by cooling the circulating water system during the photocatalytic hydrogen evolution
132 reaction.

133 The apparent quantum efficiency (AQE) for hydrogen evolution was measured using the
134 same experimental conditions, except that the Xe lamp equipped with a band-pass filter ($\lambda =$

135 420 ± 10 nm, 450 ± 10 nm, 475 ± 10 nm, 550 ± 10 nm). The light intensity is obtained with an
 136 optical power meter (CEL-NP2000, Beijing). The AQE was calculated as follows:

$$137 \quad P = \times A_R \quad (\text{Equation S1})$$

$$138 \quad N_P^i = \frac{Pt\lambda}{hc} \quad (\text{Equation S2})$$

$$139 \quad N_e = 2 \times n_{H_2} \times N_A \quad (\text{Equation S3})$$

$$140 \quad \text{AQE} = \frac{N_e}{N_P^i} \times 100\% \quad (\text{Equation S4})$$

141 **S1.5 Computation methods**

142 Differential charge density analysis and density of states of BCN and EHTD-CN were
 143 performed based on the density function theory (DFT) calculations implemented in the Vienna
 144 *ab initio* simulation package (VASP) code[1-4]. The projected augmented wave (PAW) method
 145 within the generalized gradient approximation of Perdew, Burke, and Ernzerhof (PBE) was
 146 selected to treat exchange-correlation effects[5]. To minimize the interaction between
 147 neighboring slabs, a 15 Å vacuum region was chosen as the periodic boundary condition. The
 148 energy cutoff was 500 eV. The atomic positions were relaxed until forces on each atom were
 149 less than 0.02 eV/Å. For the geometry optimization, a Monkhorst-Pack grid of $3 \times 3 \times 1$ *k*-point
 150 was adopted. For the static calculations, a Monkhorst-Pack grid of $7 \times 7 \times 1$ *k*-point was adopted.
 151 Then, based on the optimized crystal structure, the electronic structures were calculated.

152 The calculations of surface electrostatic potential, Frontier molecular orbital calculation,
 153 and Gibbs free energy for hydrogen absorption were carried out with the Gaussian software
 154 program with B3LYP and a 6-31G* basis set. The HOMO, LUMO distributions, and electrostatic
 155 potential (ESP) were obtained and mapped using the Multiwfn program and VMD software.
 156 The adsorption energy of H (ΔE_{H^*}) on BCN and EHTD-CN were defined as $E_{H^*} = E_{\text{EHTD-CN+H}^*} -$
 157 $E_{\text{EHTD-CN}} - 1/2E_{H_2}$, where $E_{\text{EHTD-CN+H}^*}$ and $E_{\text{EHTD-CN}}$ are the total energies of EHTD-CN with and
 158 without H adsorption, respectively, and E_{H_2} represents the energy of a H_2 molecule. The H
 159 adsorption free energy (ΔG_{H^*}) was defined as follows [6]:

$$160 \quad G_{H^*} = E_{H^*} - \Delta E_{\text{ZPE}} - T\Delta S$$

161 where ΔE_{ZPE} and ΔS are the changes in zero-point energy and entropy between H desorption
 162 and adsorption, respectively.

163 **S1.6 Probe-labeled EPR measurement**

164 TEMPO-labeled EPR measurement for e⁻: 1 mg of prepared samples (BCN, NTD-CN and
165 EHTD-CN) were dispersed into 1 mL of deionized water (containing 10 vol% TEOA) and
166 sonicated for 30 min. The 5 μL of TEMPO solution (10 mM) serving as a trapping agent for e⁻
167 was added into 45 μL of the above aqueous solution.

168 DMPO-labeled EPR measurement for •O- 2: 1 mg of prepared samples (BCN, NTD-CN and
169 EHTD-CN) were dispersed into 1 mL of methanol and sonicated for 30 min. The 5 μL of DMPO
170 serving as a trapping agent for •O- 2 was added into 45 μL of the above methanol solution.

171 Subsequently, the well-mixed solution was irradiated for 10 min with a 300 W xenon lamp
172 as a light source. Next, the solution before and after illumination was drawn separately with
173 a capillary tube and carefully placed into the sample chamber of the EPR spectrometer to
174 obtain the EPR spectra. The scan number was set as 5 times.

175 **S1.7 The calculation method for the built-in electric field**

176 The strength of the built-in electric field can be described by Poisson's equation[7-9]:

$$177 \quad E = \frac{eN_d}{\epsilon_0 \epsilon_r W(V_s)} \quad (\text{Equation S5})$$

178 where eN_d is the surface charge density, here defined as -ρ; The ε₀ and ε_r are the dielectric
179 constant of the graphitic carbon nitride and vacuum dielectric constant, respectively. W(V_s) is
180 the width of the space charge region, which can be described as:

$$181 \quad W(V_s) = \sqrt{\frac{2\epsilon_0 \epsilon_r V_s}{eN_d}} \quad (\text{Equation S6})$$

182 Therefore,

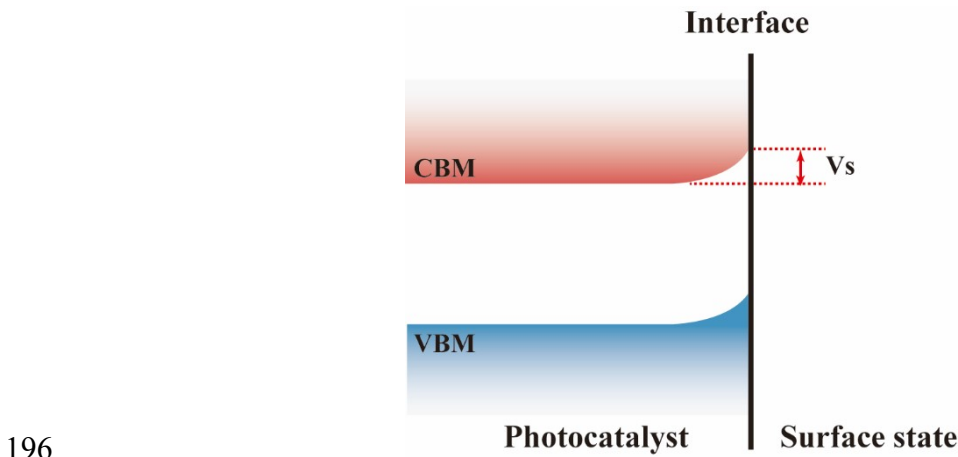
$$183 \quad E = \sqrt{\frac{-2 \rho V_s}{\epsilon_0 \epsilon_r}} \quad (\text{Equation S7})$$

184 Here, V_s is the surface response voltage, which can be measured by OCPT. As illustrated in
185 Figure S1, given that the Fermi level of the n-type semiconductor locates above its surface
186 states, when the photocatalyst is subjected to light exposure, electrons near the surface travel
187 across the interface to the catalyst surface. This induces significant band bending and,
188 consequently, a photovoltage signal that qualifies as a surface response voltage. When the
189 light is extinguished, the robust built-in electric field effectively curbs charge recombination,
190 thereby resulting in a slow decay (Figure 7i).

191 In addition, ρ can be measured by integrating the step region of the photocurrent response
 192 curve.

193 Normalizing the strength of the built-in electric field for BCN is to 1, the relative built-in
 194 electric field strength is:

$$195 \quad = \sqrt{\frac{\rho V_s}{(\rho V_s)_{\text{BCN}}}} \quad \text{(Equation S8)}$$



197 **Figure S1.** Space-charge region of an n-type semiconductor at the interface.

198

199 S1.8 The calculation method for other data

200 a) Calculations for charge carrier density (N_D)

201 According to the Equation S5 and Equation S6, the charge carrier density (N_D) of various
 202 photocatalytic materials can be calculated:

$$203 \quad \frac{1}{C^2} = \left[\frac{2}{e\epsilon\epsilon_0} \right] \times \left(E - E_{\text{fb}} - \frac{k_B T}{e} \right) \quad \text{(Equation S9)}$$

$$204 \quad N_D = \left(\frac{2}{e\epsilon\epsilon_0} \right) \times \left(\frac{d}{dE} \frac{1}{C^2} \right)^{-1} \quad \text{(Equation S10)}$$

205 where C refers to the capacitance of space charge layer, e represents the elementary charge
 206 (1.602×10^{-19} C), ϵ and ϵ_0 are the dielectric constant of graphitic carbon nitride ($\epsilon = 5.25$) and
 207 vacuum permittivity ($\epsilon_0 = 8.85 \times 10^{-14}$ F/m²), respectively, E and E_{fb} denote the applied bias
 208 potential and flat-band potential, k_B and T signify the Boltzmann constant (1.38×10^{-23} J/K)
 209 and Kelvin temperature, respectively [8].

210

211 b) Calculations for exciton binding energy (E_b):

212
$$I(T) = \frac{I_0}{1 + A \times \exp\left(\frac{-E_b}{k_B T}\right)}$$
 (Equation S11)

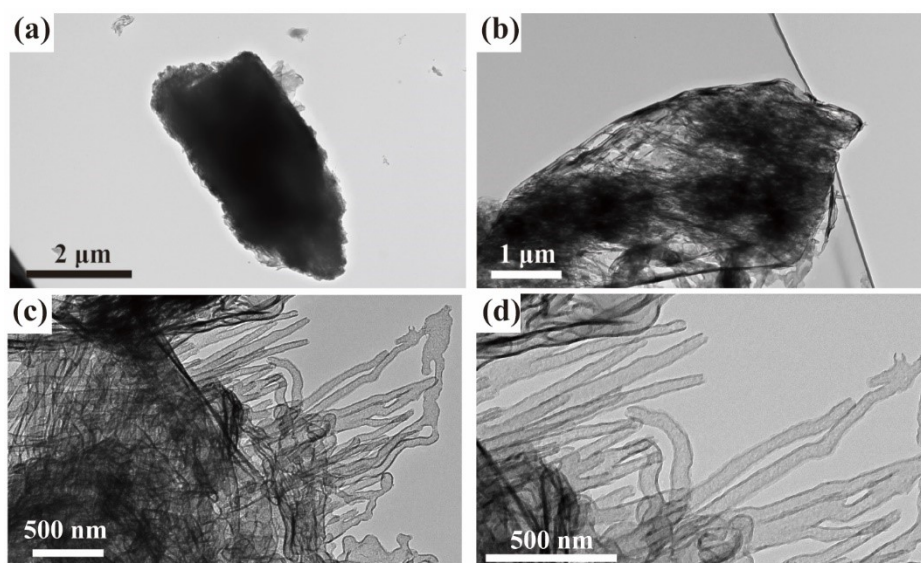
213 where I_0 and $I(T)$ represent the PL intensity at 0 K and tested temperature (T), k_B and stand
 214 for the Boltzmann constant (1.38×10^{-23} J/K) and Kelvin temperature, respectively [10].

215 Calculations for excitons dissociation efficiency (DE):

216
$$DE = \exp\left(\frac{-E_b}{k_B T}\right)$$
 (Equation S12)

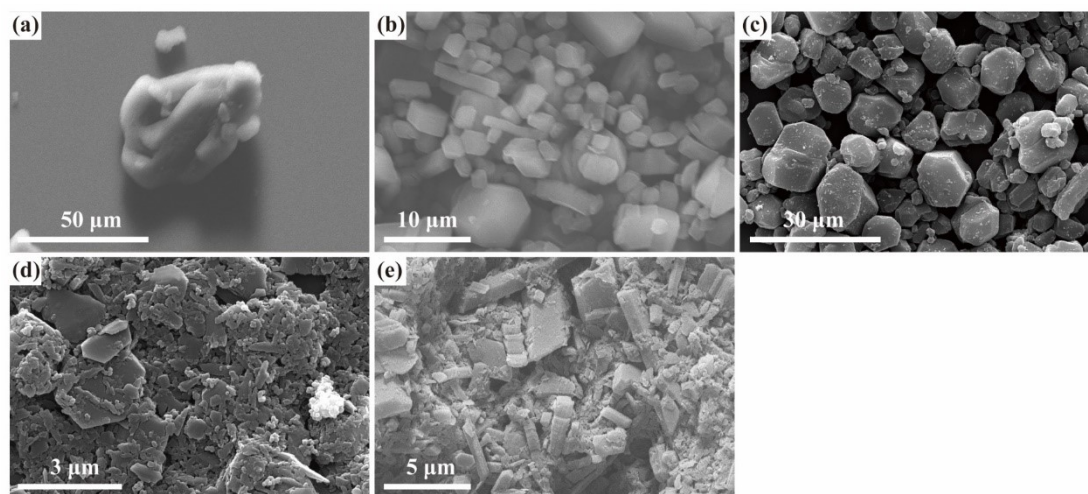
217 where $k_B T \approx 25$ meV at room temperature.

218 **S2. Supplementary Figures and Tables**



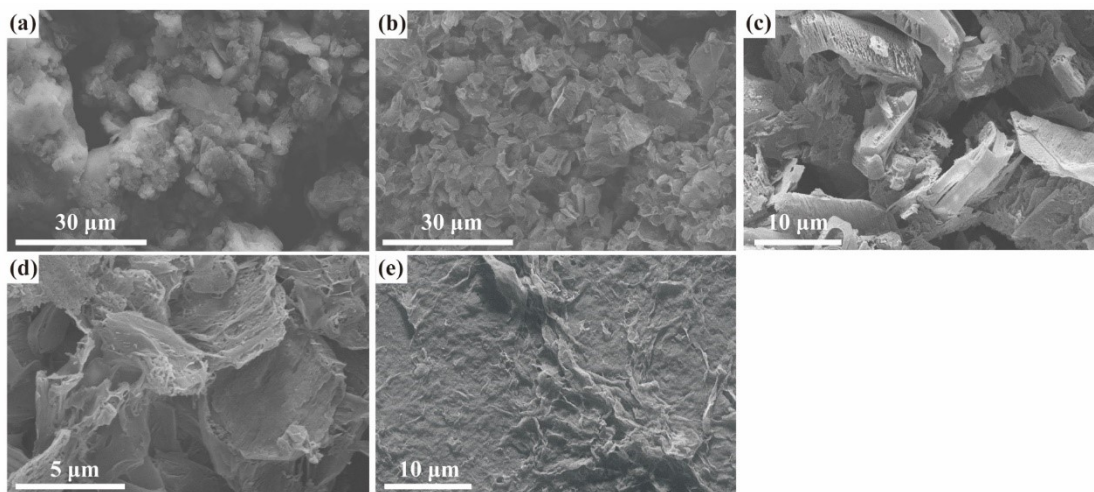
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220 **Figure S2.** TEM images of (a) BCN, (b) NTD-CN, and (c–d) EHTD-CN.



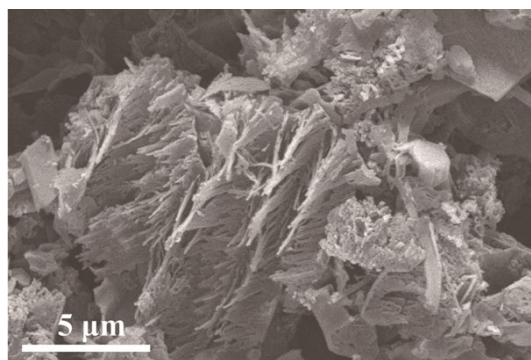
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222 **Figure S3.** SEM images of (a) commercial melamine and (b) MCA-NTD, (c) MCA-HTD, (d) MCA-
223 ETD, (e) MCA-EHTD supramolecular precursors.



224

225 **Figure S4.** SEM images of (a) BCN, (b) NTD-CN, (c) HTD-CN, (d) ETD-CN, (e) EHTD-CN samples.



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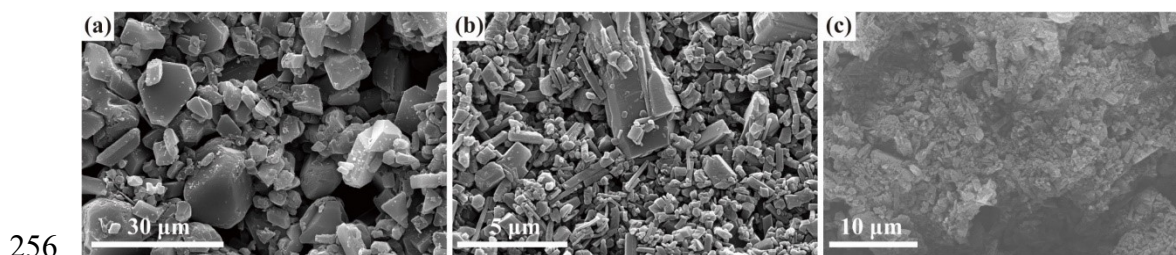
227 **Figure S5.** SEM image of EHTD-CN-BA-0.6.

228 SEM images of commercial melamine and various precursors are presented in Figure
 229 S3. As expected, commercial melamine exhibits an irregular blocky morphology.
 230 Owing to the similar molecular structure of barbituric acid to melamine and cyanuric
 231 acid, coupled with its low addition amount, the morphologies of MCA-NTD and MCA-
 232 HTD supramolecular intermediates show no significant distinction, both displaying a
 233 characteristic hexagonal prism appearance. Since the solvent polarity affects the
 234 hydrogen bonding strength between supramolecular building blocks, weakly polar
 235 ethanol impedes the self-assembly process [11], leading to a morphological
 236 transformation in MCA-ETD from prismatic structures to worm-like agglomerates.
 237 Subsequently, the morphology of MCA-EHTD undergoes further fragmentation upon
 238 the coexistence of barbituric acid and ethanol. These observations are in good

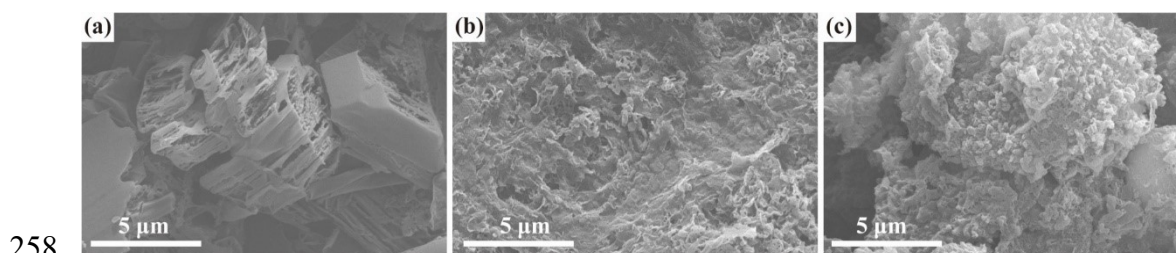
239 agreement with the morphological evolution of synthesized g-C₃N₄ samples (Figure
240 S4–Figure S7).

241 Consistent with the evolution principle observed in the supramolecular precursors,
242 BCN exhibits significant bulk agglomeration. In contrast, NTD-CN and HTD-CN, derived
243 from the polymerization of hexagonal prism-like MCA-NTD and MCA-HTD
244 supramolecular intermediates, largely inherit this morphology. This structural
245 retention stems from the loosely π - π stacking of conjugated planes, forming loosely
246 accordion-like microstructure. The modulation of supramolecular self-assembly
247 process by weakly polar ethanol solvent also affects the morphology of final products.
248 As shown in Figure S4d, the original microstructure of NTD-CN collapses into lamellar
249 stacked aggregates. The morphology of EHTD-CN undergoes further exfoliation,
250 resulting in a sheet-like structure.

251 When the addition amount of barbituric acid is further increased, its similar
252 molecular structure to melamine and cyanuric acid, combined with enhanced
253 protonation effects, partially improves the supramolecular self-assembly process.
254 Consequently, EHTD-CN-BA-0.6 displays a partially damaged accordion-like
255 morphology, accompanied by irregular aggregates.



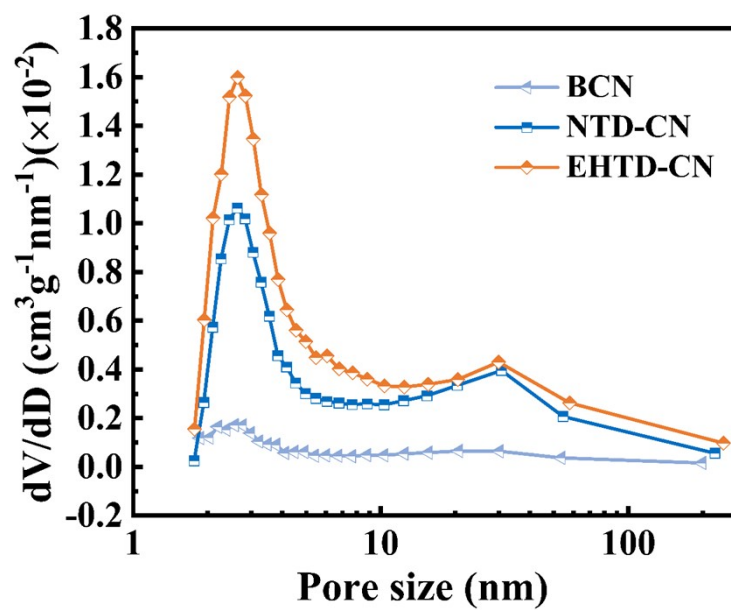
257 **Figure S6.** SEM images of (a) MCA-OH-1, (b) MCA-OH-3, and (c) MCA-OH-4.



259 **Figure S7.** SEM images of (a) EHTD-CN-OH-1, (b) EHTD-CN-OH-3, and (c) EHTD-CN-OH-4.

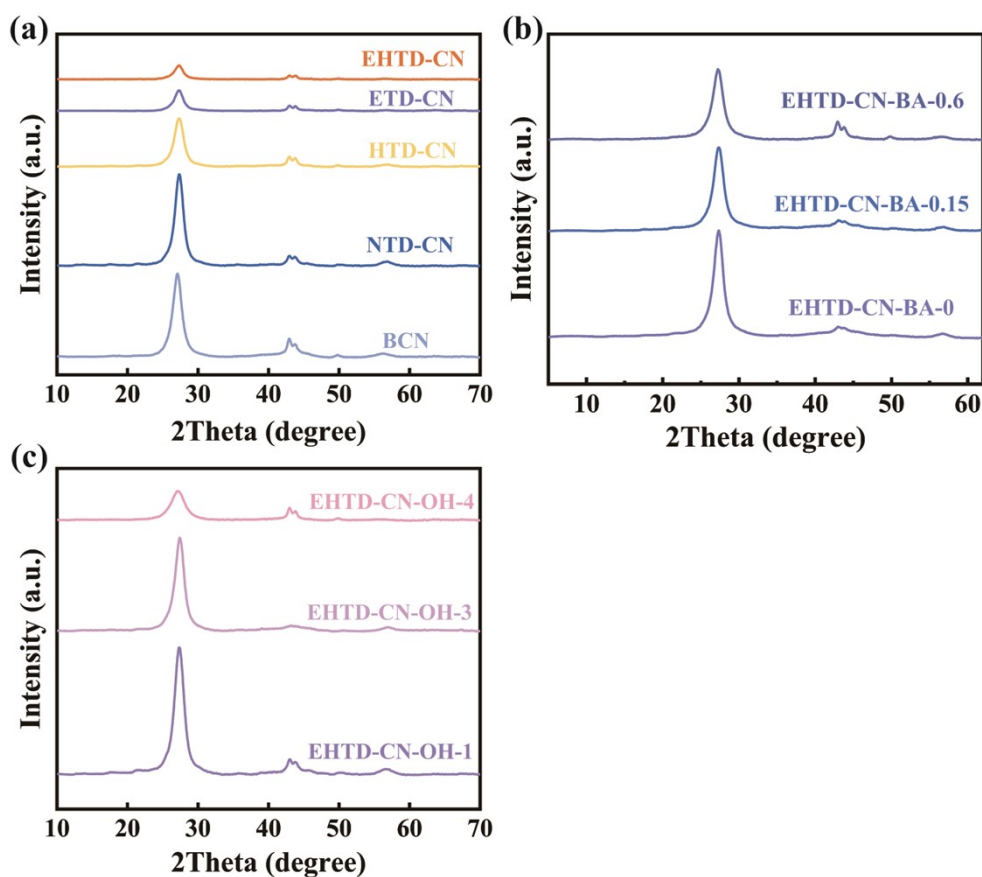
260 The regulatory effect of ethanol on the morphology evolution of supramolecular
 261 intermediates and $g\text{-C}_3\text{N}_4$ samples was investigated under the fixed barbituric acid
 262 addition. Specifically, in the strongly polar aqueous solvent, robust hydrogen bonding
 263 drives the dense stacking of supramolecular planes into hexagonal prism
 264 morphologies. The addition of ethanol impedes hydrogen bond formation between
 265 the molecules of melamine, cyanuric acid, and barbituric acid. Consequently, the
 266 hexagonal prisms progressively fragment until the weakened hydrogen bonding can
 267 no longer sustain the 3D structure of supramolecular intermediates, collapsing into
 268 irregular nanoparticles. As shown in Figure S3 and Figure S6, as the proportion of
 269 ethanol in the mixed solvent increases, the micro-morphology of MCA supramolecules
 270 gradually transforms from hexagonal prisms (MCA-NTD and MCA-HTD) to irregular
 271 microparticles (MCA-OH-1), then gradually breaks into a mixture of fragmented micro-
 272 blocks and small particles (MCA-OH-3), and finally becomes nanoscale particles (MCA-
 273 OH-4). This trend aligns consistently with the morphological evolution observed in the
 274 $g\text{-C}_3\text{N}_4$ samples (Figure S4 and Figure S7). When deionized water used as the solvent,
 275 the EHTD-CN-OH-0 (HTD-CN) exhibits a characteristic accordion-like morphology. As
 276 the ethanol/water ratio increases, the morphology of EHTD-CN-OH series samples

277 transforms from fragmented accordion-like assemblies to exfoliated sheets.
278 Subsequently, driven by a self-generated gas-bubble templating effect [12], spherical
279 bubble-like structures gradually emerge on the surface of sheet-like assemblies. This
280 ultimately transforms the morphology into a 3D architecture composed of stacked
281 spherical bubble-like structures. Collectively, these structural evolutions demonstrate
282 that barbituric acid and ethanol can synergistically modulate the morphology of EHTD-
283 CN.



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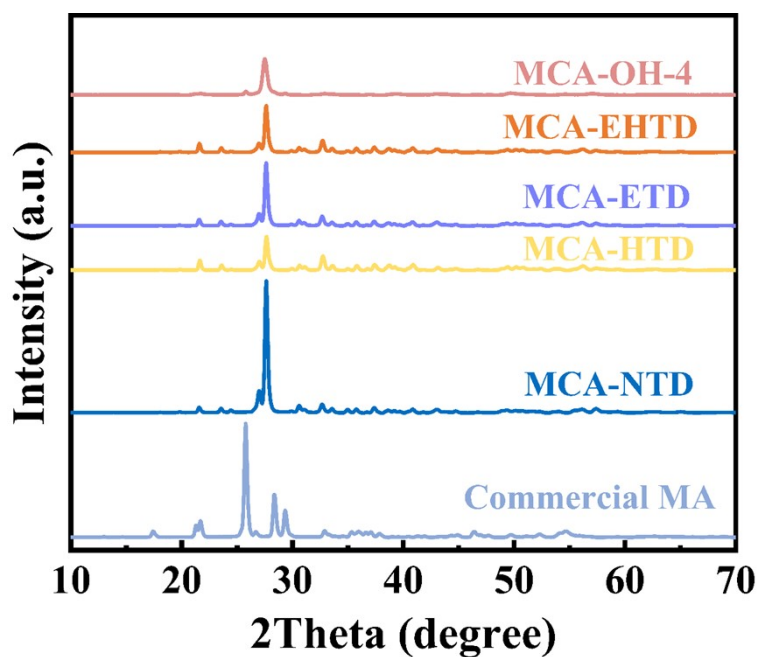
285 **Figure S8.** Pore size distribution curves of BCN, NTD-CN and EHTD-CN.



286

287 **Figure S9.** (a) XRD patterns of BCN, NTD-CN, HTD-CN, ETD-CN and EHTD-CN. (b) XRD patterns of
 288 EHTD-CN-BA0 (ETD-CN), EHTD-CN-BA0.1 and EHTD-CN-BA0.6. (c) XRD patterns of EHTD-CN-OH-1,
 289 EHTD-CN-OH-3 and EHTD-CN-OH-4.

290 The influences of the concentration of pyrimidine structures (Figure S9b) and
 291 hydroxyl groups (Figure S9c) on the physical structure of EHTD-CN were also
 292 investigated. The EHTD-CN-BA series samples exhibit distinct diffraction peaks near
 293 27.3°. Consistent with the evolution trend observed in SEM images, the diffraction
 294 peak intensity shows no significant variation, owing to the similar molecular structure
 295 of barbituric acid to melamine and cyanuric acid, coupled with the enhanced acidic
 296 environment during supramolecular self-assembly. Conversely, the participation of
 297 weakly polar ethanol disrupts the ordered self-assembly of molecular building blocks,
 298 resulting in a progressive attenuation of diffraction peak intensity in EHTD-CN-OH
 299 series samples. This also reflects the successful introduction of hydroxyl functional
 300 groups.



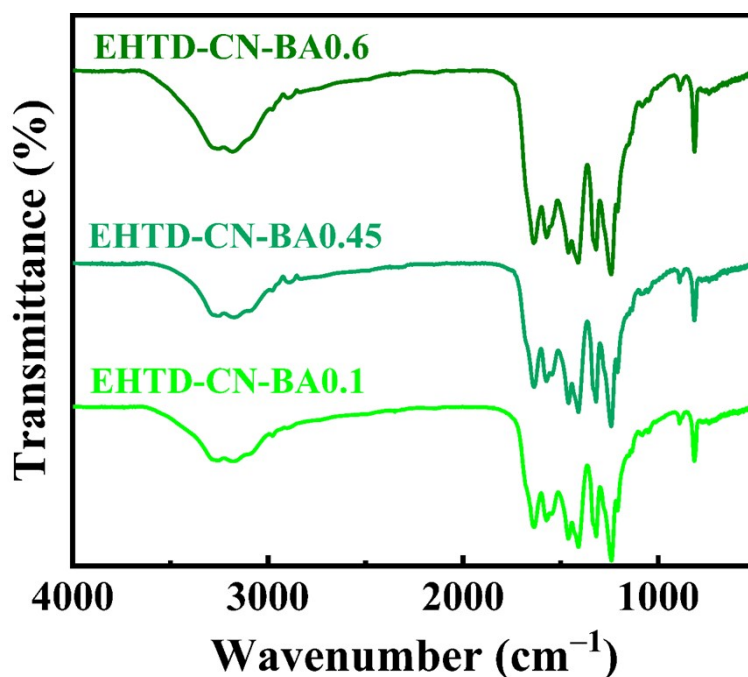
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302 **Figure S10.** XRD patterns of commercial MA and MCA-EHTD series precursors.

303 As shown in Figure S10, the powder XRD pattern of commercial melamine
 304 corresponds to monoclinic phase structure. Subsequently, MCA-NTD undergoes a
 305 transformation to an orthorhombic phase with strong diffraction peaks. This indicates
 306 that melamine and cyanuric acid undergo supramolecular self-assembly via hydrogen
 307 bonding in polar aqueous solvent, resulting in their regular stacking into the hexagonal
 308 prism morphology (Figure S3b). The incorporation of ETD and HTD does not alter the
 309 fundamental molecular framework of supramolecular intermediate. However, it leads
 310 to a gradually decrease in diffraction intensity and concomitant fragmentation of the
 311 morphology (Figure S3e).

312

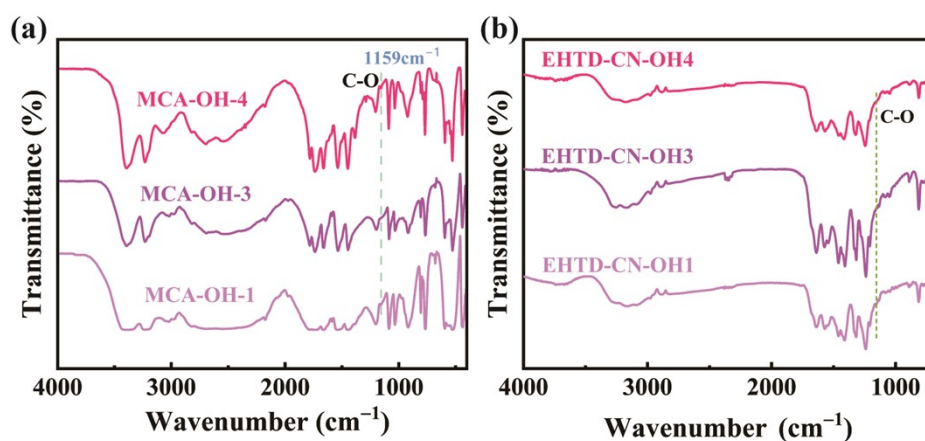
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315 **Figure S11.** FTIR spectra of EHTD-CN-BA0.1, EHTD-CN-BA0.45 and EHTD-CN-BA0.6.

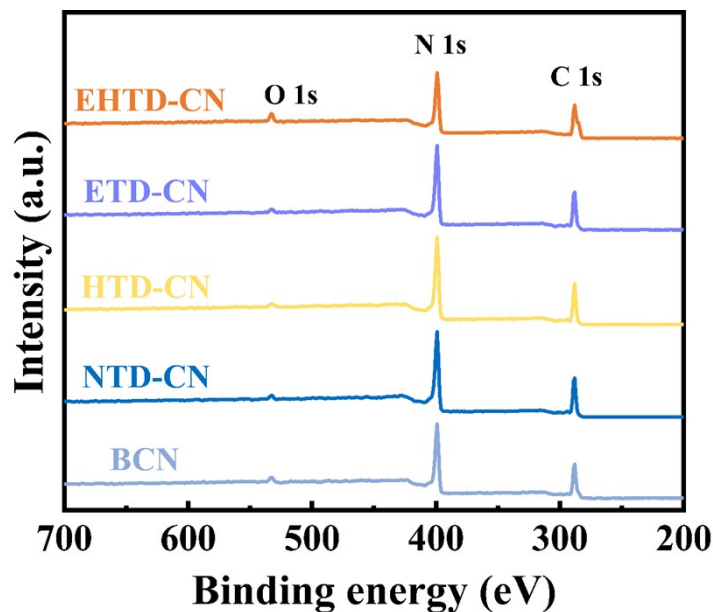
316 As shown in Figure S11, increasing barbituric acid addition during supramolecular
 317 self-assembly induces no significantly changes in the FTIR spectra of EHTD-CN-BA
 318 series samples, except for enhanced vibrational intensity of aromatic heterocycles.
 319 This confirms that pyrimidine ring incorporation does not disrupt the fundamental
 320 framework of g-C₃N₄.



321

322 **Figure S12.** FTIR spectra of supramolecular intermediates and their derived EHTD-CN-OH-1,
 323 EHTD-CN-OH-3 and EHTD-CN-OH-4.

324 The effect of ethanol/water volume ratio on the molecular structures of
325 supramolecular intermediates and corresponded g-C₃N₄ samples was further
326 investigated (Figure S12). With increasing ethanol proportion, the intensity of C-O
327 breathing vibration mode at 1159 cm⁻¹ and asymmetric stretching vibration of
328 adsorbed water/hydroxyl groups around 3280 cm⁻¹ in MCA-OH series supramolecular
329 intermediates gradually increases. These characteristic vibrations persist after
330 polymerization of the supramolecular intermediates into EHTD-CN-OH series samples.
331 This result demonstrates that the successful grafting of hydroxyl functional groups at
332 the edges of heptazine framework.



333

334 **Figure S13.** XPS spectra of full survey spectra of BCN, NTD-CN, HTD-CN, ETD-CN and EHTD-CN.

335

336 **Table S1.** The elemental analyses of samples determined by organic element analyzer.

Samples	Weight ratio (wt.%)				Atomic ratio (at.%)			
	N	C	H	O	N	C	H	C/N
BCN	60.956	34.677	2.127	11.913	46.56	30.87	22.56	0.663
NTD-CN	59.354	34.199	2.303	13.257	45.22	30.40	24.39	0.672
EHTD-CN	59.943	34.788	2.685	15.187	43.49	29.44	27.07	0.677

337

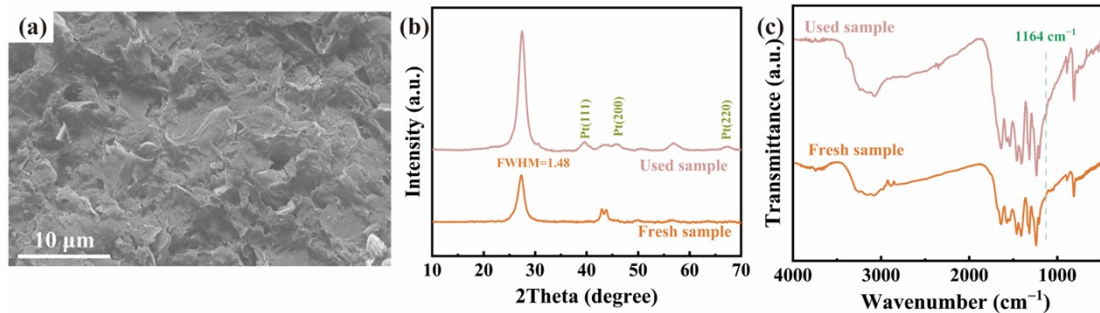
338 Elemental contents of N, C, H, and O in BCN, NTD-CN, and EHTD-CN were measured using
 339 an elemental analyzer. The N atom content in NTD-CN decreases significantly, owing to the
 340 hydrolysis of terminal amino groups during the supramolecular self-assembly. Meanwhile, its
 341 C/N ratio of 0.672 is closer to the theoretical value of 0.67 for melon-based $g\text{-C}_3\text{N}_4$, indicating
 342 that the supramolecular self-assembly is beneficial for reorganizing the molecular structure
 343 and avoiding the formation of structural defects. Subsequently, the increased C/N ratio of
 344 EHTD-CN confirms the incorporation of pyrimidine rings. Although measured O content
 345 exceeds actual values due to surface adsorbed H_2O and O_2 from ambient exposure, EHTD-CN
 346 demonstrates substantially higher O and H content than those in BCN and NTD-CN, confirming

347 the introduction of ETD. These results are well consistent with those from XPS, FTIR, NMR, and
348 other analyses.

349 **Table S2.** Comparison of the photocatalytic hydrogen production performance for EHTD-CN and other recently reported carbon nitrides.

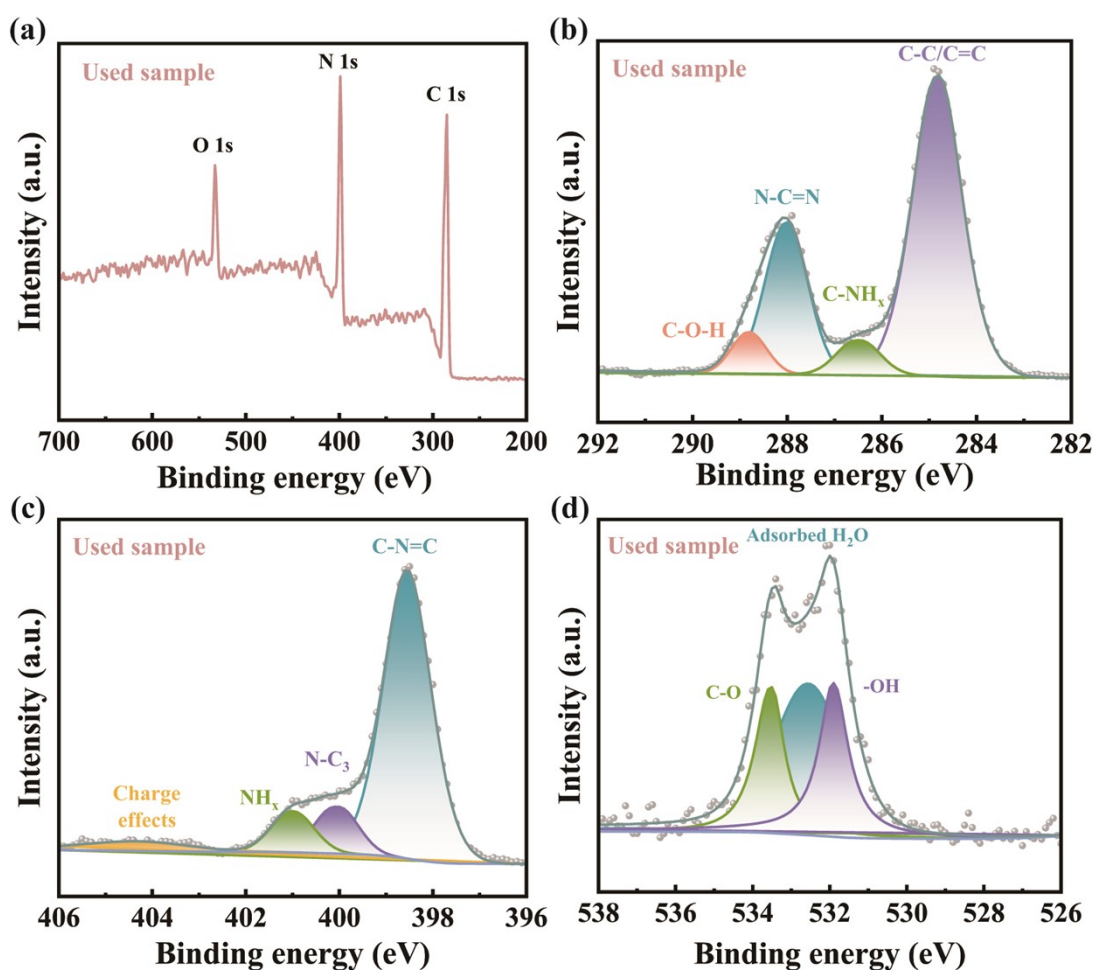
Photocatalyst	Strategy	Light source	Catalyst/ cocatalyst	Sacrificial agent	HER ($\mu\text{mol g}^{-1} \text{h}^{-1}$)	Enhancement factor	Reference
(Methyl, hydroxyl)-PHI/g-C ₃ N ₄	Post-treatment	300W Xe lamp ($\geq 400 \text{ nm}$)	50 mg/1 wt% Pt	10 vol% TEOA	1002	7.2	[13]
Polyelectrolytes/hydroxyl-g-C ₃ N ₄	Self-assembly	300W Xe lamp ($\geq 400 \text{ nm}$)	10 mg/1.5 wt% Pt	10 vol% TEOA	24010	14.6	[14]
(C, hydroxyl)-g-C ₃ N ₄	Co-polymerization	300W Xe lamp ($\geq 420 \text{ nm}$)	20 mg/1.5 wt% Pt	10 vol% TEOA	7282	17.5	[15]
Thiophene ring-doped g-C ₃ N ₄	Co-polymerization	300W Xe lamp ($\geq 420 \text{ nm}$)	50 mg/3 wt% Pt	10 vol% TEOA	10341	15.2	[16]
Aromatic rings-doped g-C ₃ N ₄	Co-polymerization	300W Xe lamp ($\geq 420 \text{ nm}$)	50 mg/3 wt% Pt	10 vol% TEOA	2042	3.5	[17]
B-doped D-A integrated g-C ₃ N ₄	Co-polymerization	300W Xe lamp ($\geq 420 \text{ nm}$)	30 mg/3 wt% Pt	10 vol% TEOA	1914	5.9	[18]
N-heterobenzene-doped g-C ₃ N ₄	Co-polymerization	300W Xe lamp ($\geq 420 \text{ nm}$)	50 mg/1 wt% Pt	10 vol% TEOA	5732	8.4	[19]
Corrugated g-C ₃ N ₄ nanosheet	Post-treatment	300W Xe lamp ($\geq 420 \text{ nm}$)	20 mg/0.5 wt% Pt	10 vol% TEOA	2485	40	[20]
P-doped low-crystalline, high-crystalline homojunction	Molten salt method	300W Xe lamp (AM 1.5)	10 mg/MoS ₂	20 vol% lactic acid	12090	40.3	[21]
(cyanamide/cyano)- g-C ₃ N ₄	Molten salt method	300W Xe lamp ($\geq 420 \text{ nm}$)	20 mg/3 wt% Pt	10 vol% TEOA	3550	13.8	[22]
Ultrathin g-C ₃ N ₄	Supramolecular assembly	300W Xe lamp ($\geq 400 \text{ nm}$)	20 mg/3 wt% Pt	10 vol% TEOA	2590	9.9	[23]
Few-layer g-C ₃ N ₄	Supramolecular assembly	300W Xe lamp ($\geq 420 \text{ nm}$)	20 mg/1 wt% Pt	20 vol% TEOA	7990	26	[24]
Corrugated g-C ₃ N ₄ nanosheet	Supramolecular assembly	300W Xe lamp ($\geq 420 \text{ nm}$)	10 mg/0.5 wt% Pt	10 vol% TEOA	5553	12	[25]
g-C ₃ N ₄ bending nanotube	Supramolecular assembly	300W Xe lamp ($\geq 420 \text{ nm}$)	50 mg/1 wt% Pt	10 vol% TEOA	4350	15.8	[26]
Porous V _N -g-C ₃ N ₄	Supramolecular assembly	300W Xe lamp ($\geq 400 \text{ nm}$)	20 mg/1 wt% Pt	10 vol% TEOA	5500	17.2	[27]
C-doped hollow porous g-C ₃ N ₄	Supramolecular assembly	300W Xe lamp ($\geq 420 \text{ nm}$)	50 mg/1 wt% Pt	10 vol% TEOA	16690	139	[28]
O-doped g-C ₃ N ₄ nanosheet	Supramolecular assembly	300W Xe lamp ($\geq 420 \text{ nm}$)	50 mg/3 wt% Pt	10 vol% TEOA	1968	11.3	[29]
P-doped g-C ₃ N ₄ tube	Supramolecular assembly	300W Xe lamp ($\geq 420 \text{ nm}$)	100 mg/1 wt% Pt	20 vol% methanol	670	7	[30]

(C, O)-doped g-C ₃ N ₄ nanobelt	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	5 mg/3 wt% Pt	10 vol% TEOA	18380	79.9	[31]
(B-doped, cyano)-g-C ₃ N ₄ tube	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	25 mg/3 wt% Pt	10 vol% TEOA	789	4	[32]
Benzene-ring-doped g-C ₃ N ₄ tube	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	50 mg/1 wt% Pt	10 vol% TEOA	2780	14.9	[33]
(Benzene-ring, O)-doped g-C ₃ N ₄	Supramolecular assembly	300W Xe lamp (AM 1.5)	10 mg/3 wt% Pt	10 vol% TEOA	13920	3.7	[34]
Porous amino-rich g-C ₃ N ₄	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	50 mg/3 wt% Pt	10 vol% TEOA	3270	6	[35]
BTH doped D-A structural g-C ₃ N ₄	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	50 mg/1 wt% Pt	10 vol% TEOA	3950	13.3	[36]
(Hydroxyl, carboxyl)-doped g-C ₃ N ₄	Supramolecular assembly	Xe lamp (≥ 420 nm)	20 mg/2 wt% Pt	30 vol% methanol	985	/	[37]
(Thiophene ring, cyano)-doped g-C ₃ N ₄	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	20 mg/3 wt% Pt	20 vol% TEOA	4177	17.9	[38]
Mesopores homojunction	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	20 mg/3 wt% Pt	10 vol% TEOA	934	5	[39]
Nanotube/nanosheet homojunction	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	10 mg/3 wt% Pt	10 vol% TEOA	9100	22.8	[40]
Nanodot/nanosheet homojunction	Supramolecular assembly	300W Xe lamp (AM 1.5)	10 mg/3 wt% Pt	10 vol% TEOA	21794	10.6	[41]
Pt-N ₃ /g-C ₃ N ₄	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	20 mg/none	10 vol% TEOA	9750	15.4	[42]
Ag-N ₂ C ₂ /g-C ₃ N ₄	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	20 mg/none	10 vol% TEOA	1866	/	[43]
Ag ₁ Co ₁ -g-C ₃ N ₄	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	20 mg/none	10 vol% TEOA	1190	/	[44]
C dots/S-doped g-C ₃ N ₄ tube/NiPc	Supramolecular assembly	300W Xe lamp (AM 1.5)	5 mg/1 wt% Pt	10 vol% TEOA	16363	23.2	[45]
Curled g-C ₃ N ₄ nanobelt (NTD-CN)	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	50 mg/3 wt% Pt	10 vol% TEOA	440	4.4	This work
(ETD, HTD)-synergetic g-C ₃ N ₄	Supramolecular assembly	300W Xe lamp (≥ 420 nm)	50 mg/3 wt% Pt	10 vol% TEOA	3090	30.9	This work



351

352 **Figure S14.** (a) SEM image of used EHTD-CN after recycling tests, (b) XRD patterns and (c) FTIR
 353 spectra of fresh sample and used sample.

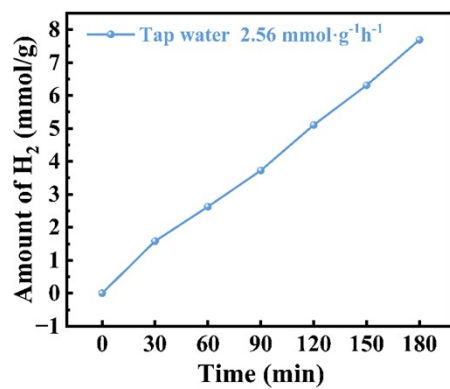


354

355 **Figure S15.** XPS spectra of used sample after 12 h cycling experiments, (a) full survey spectra, (b)
 356 C 1s, (c) N 1s, (d) O 1s high-resolution spectra.

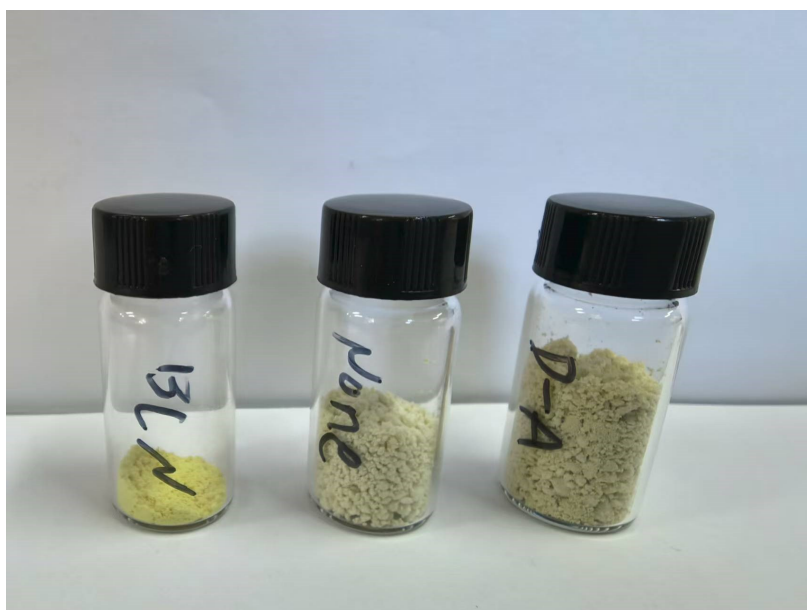
357 As shown in Figure S15, the XPS survey spectrum of post-cycling samples confirms
 358 the exclusive presence of C, N, and O elements. High-resolution C 1s deconvolutions
 359 exhibit four characteristic peaks at 284.8, 286.47, 288.1, and 288.81 eV, assigned to C-

360 C/C=C from adventitious carbon or pyrimidine structures, terminal C-NH_x, sp²
361 hybridized N-C=N, and C-OH, respectively. High-resolution N 1s spectrum exhibits
362 characteristic peaks corresponding to C-N=C, N-C₃, NH_x, and π excitation, respectively.
363 High-resolution O 1s spectrum resolve three components at 531.89, 532.56, and
364 533.50 eV, assigned to hydroxyl groups (-OH), surface-adsorbed H₂O, and C-O,
365 respectively. The robust BIEF with EHTD-CN facilitates monodisperse distribution of Pt
366 cocatalysts and its low loading amount, resulting in no discernible Pt signals in XPS
367 spectrum. These results demonstrate unchanged chemical composition after 12 h
368 operation, underscoring its exceptional structural integrity and high practical
369 applicability. Notably, relative to the pristine g-C₃N₄, positive binding energy shifts in
370 heptazine rings and terminal NH_x groups attributes to h⁺ accumulation at HTD sites
371 (oxidation centers). Concurrently, slight positive shifts of binding energy in C-O/-OH
372 results from electron extraction from ETD (photogenerated electron-rich sites) by Pt
373 nanodots with high work function.



374

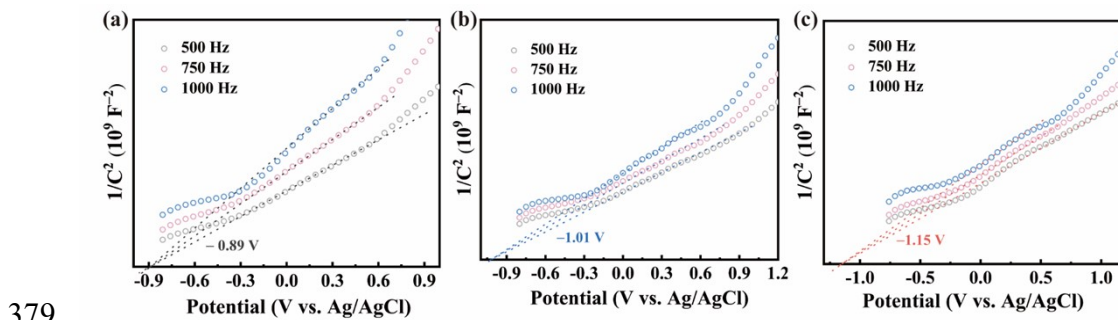
375 **Figure S16.** Photocatalytic hydrogen evolution curve of EHTD-CN in tap water.



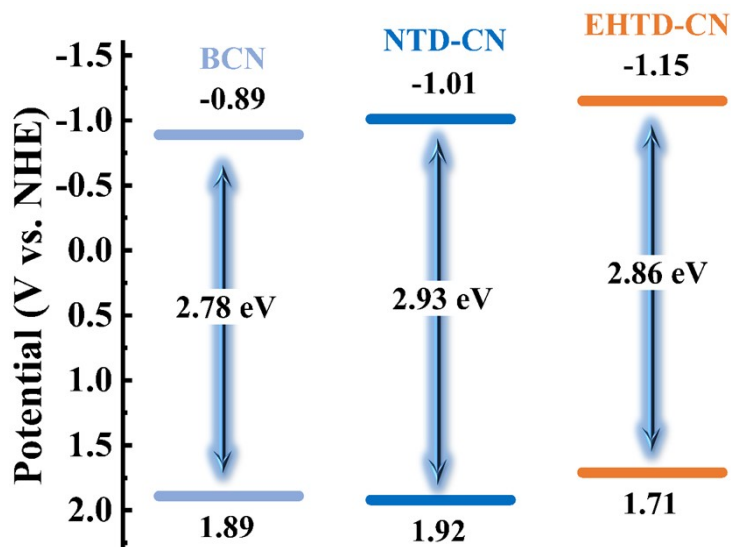
376

377 **Figure S17.** Macroscopic photograph of 0.1g of BCN (left), NTD-CN (middle), and EHTD-CN (right).

378



380 **Figure S18.** Mott-Schottky curves of (a) BCN, (b) NTD-CN and (c) EHTD-CN.



382 **Figure S19.** Schematic band structure of BCN, NTD-CN and EHTD-CN.

383 As evidenced by the Mott-Schottky plots in Figure S17, all samples exhibit positive
 384 slopes across three measured frequencies, confirming n-type semiconductor
 385 behavior. In addition, the flat-band potential of BCN, NTD-CN, and EHTD-CN,
 386 evaluated from the tangent intercept of linear portions with the x-axis, are measured
 387 as -0.89 , -1.01 , and -1.15 V vs. Ag/AgCl, respectively. Converting these values to the
 388 normal hydrogen electrode (NHE) via Equation S9 gives -0.89 , -1.01 , and -1.15 V vs.
 389 NHE. For n-type semiconductors, the conduction band minimum (CBM) is typically 0.2
 390 eV more negative than its flat-band potential. Thus, their CBM are estimated to be
 391 -0.89 , -1.01 , and -1.15 V vs. NHE, respectively. Subsequently, their valence band
 392 maxima are calculated as 1.89, 1.92, and 1.71 V vs. NHE, respectively.

393 The resulting band alignments are schematically illustrated in Figure S18. Quantum
394 confinement in ultrathin curled nanobelts widens the bandgap of NTC-CN. EHTD-CN
395 displays a more negative CBM, thermodynamically favoring proton reduction to H₂.

396
$$E_{\text{NHE}} = E_{\text{Ag/AgCl}} + 0.197 \text{ V} \quad (\text{Equation S13})$$

397
$$E_{\text{VB}} - E_{\text{CB}} = E_{\text{g}} \quad (\text{Equation S14})$$

398 Moreover, according to the equation S11:

399
$$E_{\text{VB-NHE}} = \Psi + E_{\text{VB-XPS}} - 4.44 \quad (\text{Equation S15})$$

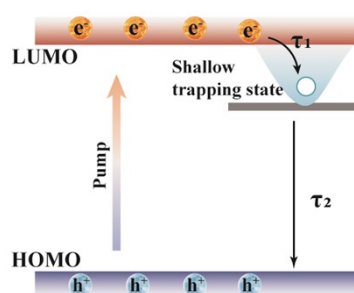
400 where Ψ is the instrumental work function (4.5 eV). The obtained $E_{\text{VB-XPS}}$ potential can
401 be converted into $E_{\text{VB-NHE}}$, thus the VBM potentials of BCN, NTD-CN and EHTD-CN are
402 1.85 V, 1.90 V, and 1.70 V vs. NHE, respectively. These results are almost consistent
403 with the band structure obtained from Mott-Schottky curves, further confirming their
404 reliability.

405 **Table S3.** Slope values obtained from the Mott-Schottky plots at 1000 Hz for BCN, NTD-CN, and
406 EHTD-CN.

Samples	Slope values
BCN	2.21×10^{11}
NTD-CN	9.43×10^{10}
EHTD-CN	4.75×10^{10}

407

408 Furthermore, charge carrier densities were quantified via the slope of Mott-
409 Schottky curves at 1000 Hz (Text S1.8). Generally, a smaller slope unequivocally
410 reflects a higher charge carrier density. Owing to the robust BIEF, EHTD-CN exhibits
411 the smallest Mott-Schottky slope, thereby evidencing its largest charge carrier density.



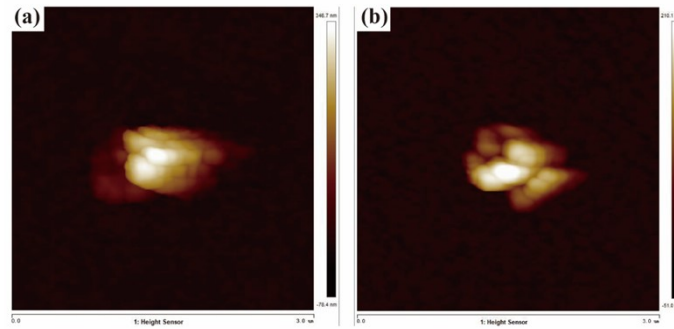
412

413 **Figure S20.** Schematic diagram of TA signal at different timescales for BCN.

414

415 **Table S4.** The fitted decay dynamics of BCN and EHTD-CN.

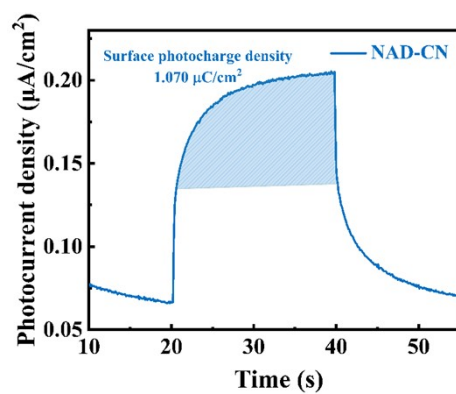
Component	τ_1 (ps)	A_1 (%)	τ_2 (ps)	A_2 (%)	τ_3 (ps)	A_3 (%)	τ_{ave} (ps)
BCN	146.44	11.94	1296.49	88.06	/	/	1159
EHTD-CN	106.64	2.45	535.88	11.45	3144.35	86.10	2771



417

418 **Figure S21.** KPFM surface morphologies of BCN and EHTD-CN.

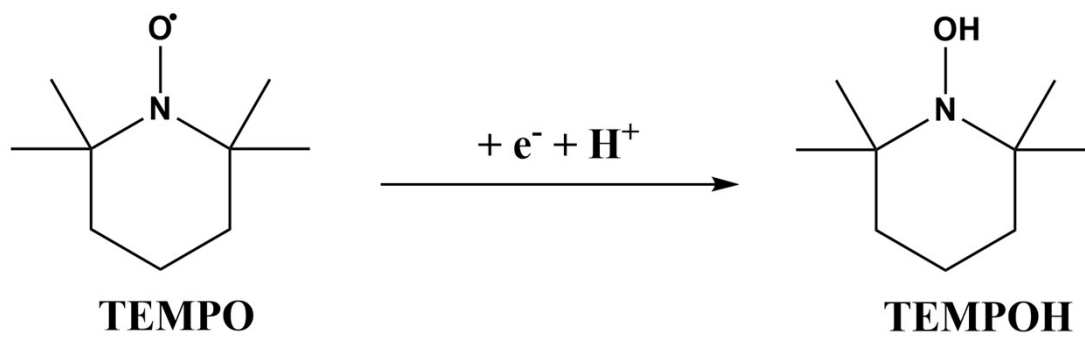
419 To accurately probe exciton dissociation and charge carrier dynamics, KPFM
420 measurements were conducted on the regions with comparable microstructure and
421 height profiles, eliminating the potential artifacts from topographic variations or
422 sample content. Figure 6a–d reveal positive surface potential signals across all
423 samples due to electron transfer to the ITO substrate, a characteristic manifestation
424 of n-type semiconductor behavior (potential scale uniformly calibrated). The synergy
425 of ETD and HTD enhances polarization within EHTD-CN, yielding a stronger contact
426 potential difference (-76.6 mV), which manifests as a pronounced low-potential
427 regions at the center of its potential distribution mapping. Upon illumination, the
428 robust BIEF in EHTD-CN promotes efficient exciton dissociation into free charge
429 carriers, consequently indicating a more significant decrease in contact potential
430 difference compared to BCN.



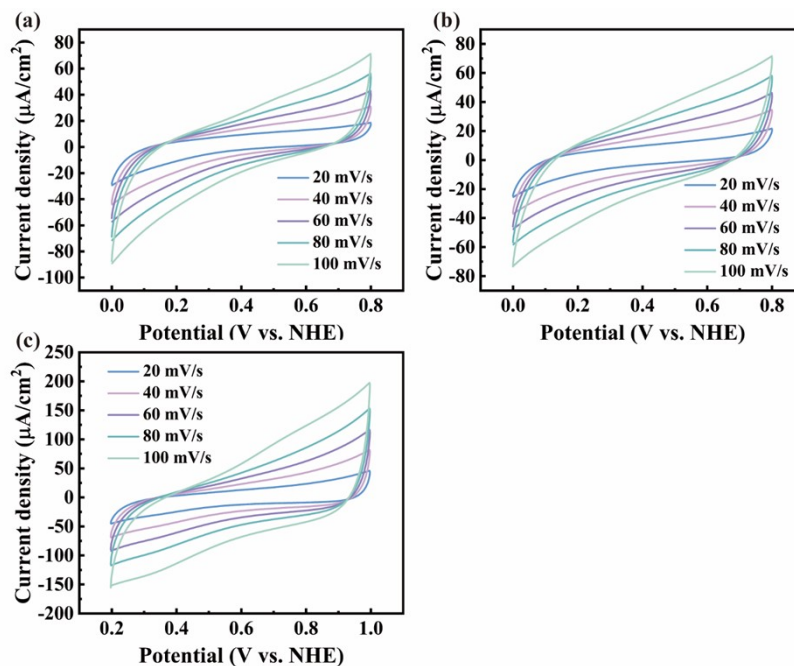
431

432 **Figure S22.** Surface photocharge density of NTD-CN.

433



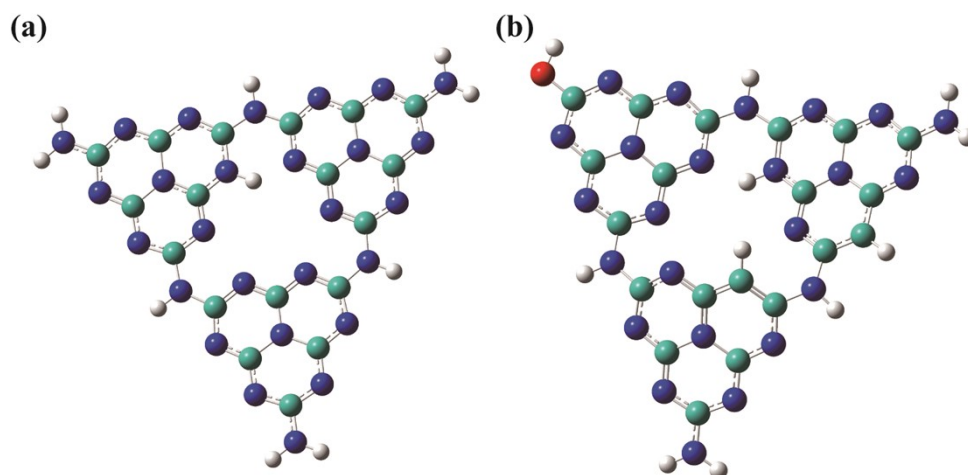
435 **Figure S23.** Schematic diagram of the conversion process for the reduction of TEMPO to TEMPOH
436 by electrons.



437

438 **Figure S24.** Cyclic voltammetry curves of (a) BCN, (b) NTD-CN and (c) EHTD-CN at different scan
 439 rates.

440 Cyclic voltammetry (CV) measurements for BCN, NTD-CN, and EHTD-CN were
 441 performed. Generally, a larger integrated area in CV curves reflects a higher specific
 442 capacitance, signifying greater number of electrons available for reduction [46].
 443 Variations in scan rate do not alter the characteristic shape of CV curves. However, as
 444 the scan rates increase, the current density and corresponding CV curve area increase
 445 for all samples. Notably, EHTD-CN exhibits a substantially larger CV curve area
 446 compared to BCN and NTD-CN, indicating a greater population of available free
 447 electrons. The double-layer capacitances (C_{dl}), proportional to the electrochemically
 448 active surface area (ECSA), were determined by fitting the linear relationship between
 449 the scan rate and current density. NTD-CN shows only a marginal enhancement in
 450 ECSA relative to BCN. In stark contrast, EHTD-CN demonstrates a significantly
 451 increased ECSA. This trend in ECSA directly correlates with the photocatalytic
 452 hydrogen production, highlighting that the simultaneous incorporation of ETD and
 453 HTD markedly increases the density of active sites on the photocatalyst surface.



454

455 **Fig. S25.** The calculation model of H* adsorption free energy for (a) BCN and (b) EHTD-CN. (N, blue; C,
456 cyan; O, red; H, white)

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